

T510E107M025ATE050

T510, Tantalum, MnO₂ Tantalum, Multi-Anode, 100 uF, 20%, 25 VDC, SMD, MnO₂, Molded, Large Case, Multi-Anode, LowESR, 50 mOhms, 3.8 mm, 2824 / 7360



Click [here](#) for the 3D model.

General Information

Series	T510
Dielectric	MnO ₂ Tantalum
Style	SMD Chip
Description	SMD, MnO ₂ , Molded, Large Case, Multi-Anode, LowESR
Features	Low ESR
RoHS	Yes
Termination	Tin
Typical Component Weight	500.73 mg
Shelf Life	156 Weeks
MSL	1

Dimensions

L	7.3mm +/-0.3mm
W	6mm +/-0.3mm
H	3.6mm +/-0.2mm
T	0.13mm REF
S	1.3mm +/-0.3mm
F	4.1mm +/-0.1mm
A	3.8mm MIN
B	0.5mm +/-0.15mm
E	3.5mm REF
G	3.5mm REF
X	0.1mm +/-0.1mm REF

Packaging Specifications

Packaging	T&R, 178mm
Packaging Quantity	500

Specifications

Capacitance	100 uF
Tolerance	20%
Voltage DC	25 VDC (85C), 16.75 VDC (125C)
Temperature Range	-55/+125°C
Rated Temperature	85°C
Dissipation Factor	8% 120Hz 25C
Failure Rate	N/A
ESR	50 mOhms (100kHz 25C)
Ripple Current	2387 mA (rms, 100kHz 25C), 2148.3 mA (rms, 85C), 954.8 mA (rms, 125C)
Leakage Current	25 uA (5min 25°C)

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